
3-Channel GPS/GLONASS/Galileo/BeiDou/IRNSS/QZSS S/L1/L2/L3/L5 bands RF Front End

SPECIFICATION

1 FEATURES

Overall

- 3 independent, fully customizable channels
- 3 coherent fractional-N PLLs with fully integrated VCOs and auto-tuning system
- Clock output for correlator with programmable frequency, amplitude and DC level
- Pass-through TCXO reference signal output
- I2C interface
- Embedded temperature sensor
- Few external components
- 12x12mm QFN108 package

Channels #1 and #2 feature list:

- Single conversion super heterodyne structure channels
- Integrated LNA
- Integrated active antenna input buffer including short-protected antenna supply circuit
- Tunable passband with auto-calibration system
- Output signal manual selection: complex or real with separate upper and lower sideband
- Analog differential output or 2-bit ADC digital output with programmable thresholds and output logic high level
- 3-wire SPI access to control registers

Channel #3 feature list:

- Direct conversion structure channel for S-band IRNSS reception
- Dual AGC system (RF + IF) or manually programmable gain
- Wide dynamic range with 1dB compression point up to +7 dBm
- Receiving RTK data over FM 65...110 MHz, VHF 160...240 MHz, UHF 470...862 MHz bands

2 APPLICATION

- Navigation systems
- Portable receivers
- Mobile communication
- Measuring equipment

3 OVERVIEW

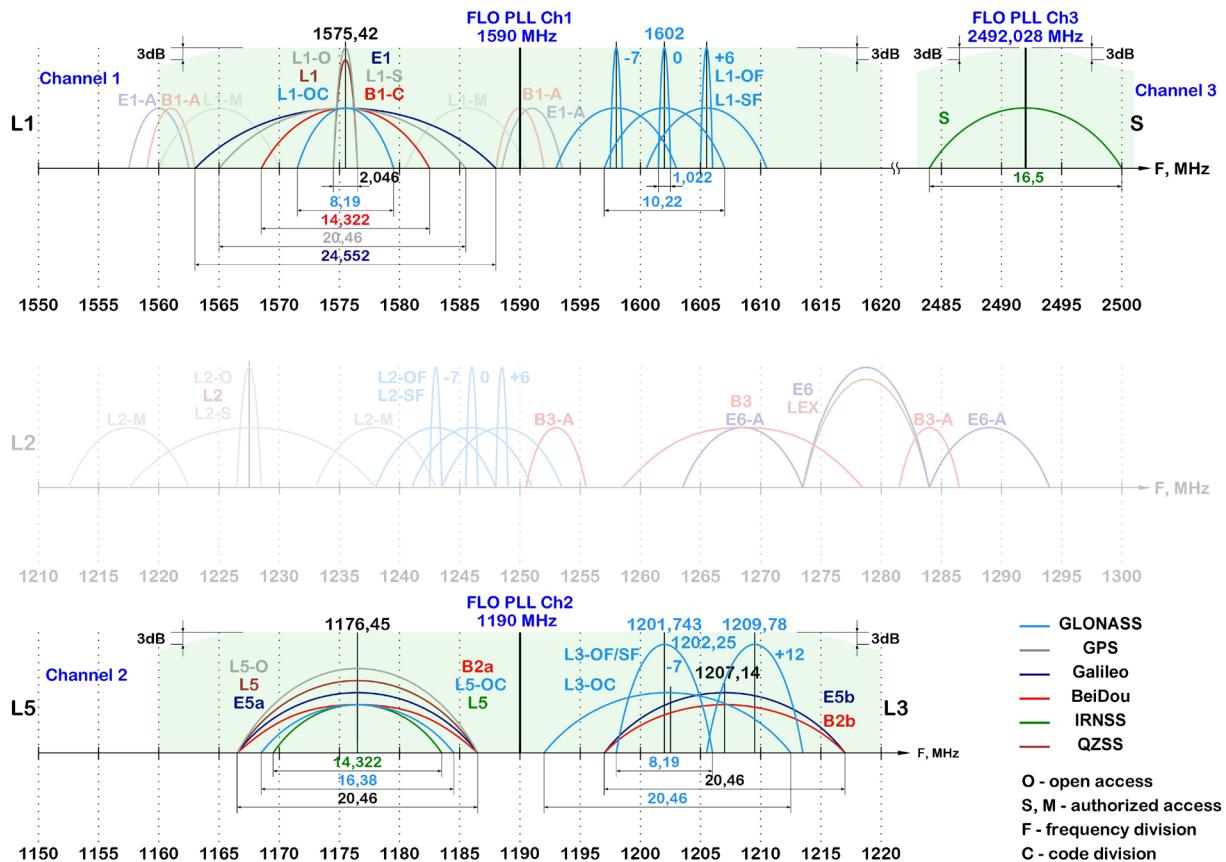
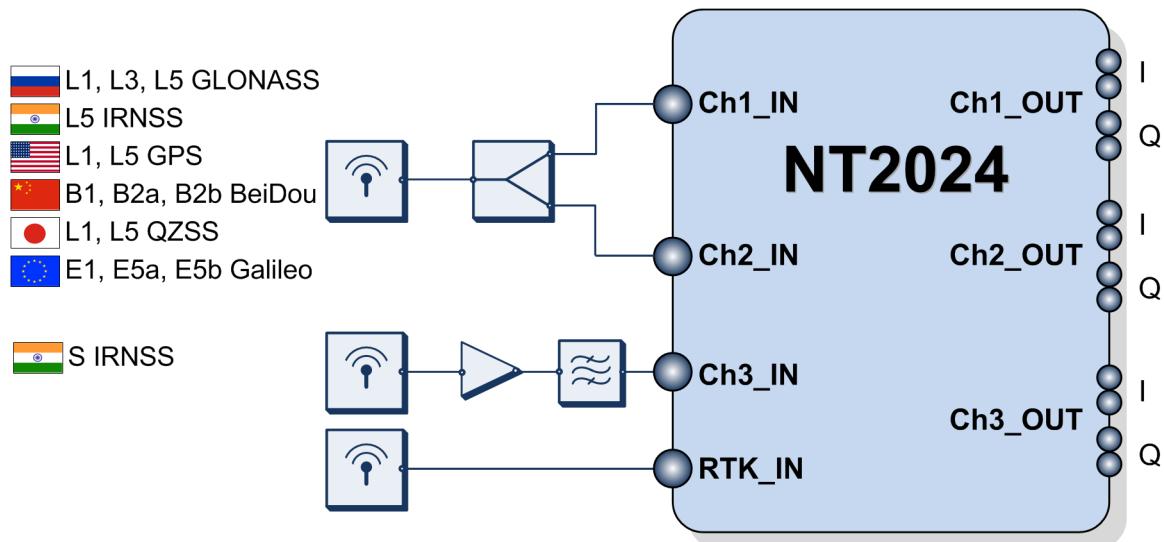
NT2024 is a 3-channel RF Front End that covers all GNSS (GLONASS, IRNSS, GPS, Galileo, BeiDou, QZSS) signals at all frequency bands. It makes possible to benefit from all the advantages of acquiring multiple systems. Channels #1 and #2 are designed with single conversion low-IF architecture, individually programmable and intended to receive either L1, E1, B1 or E6, B3, L2, L3, B2, L5, E5 in different combinations. IQ and image suppression modes are available, other options can be discovered in feature list. Channel #3 is dedicated to operate on S band of IRNSS and has zero-IF architecture. This special addition makes possible to effectively eliminate ionospheric distortion utilizing large signal base of IRNSS between L5

and S bands. As alternative, channel#3 can be software-reconfigured to receive real-time corrections data transmitted over FM, VHF and UHF bands.

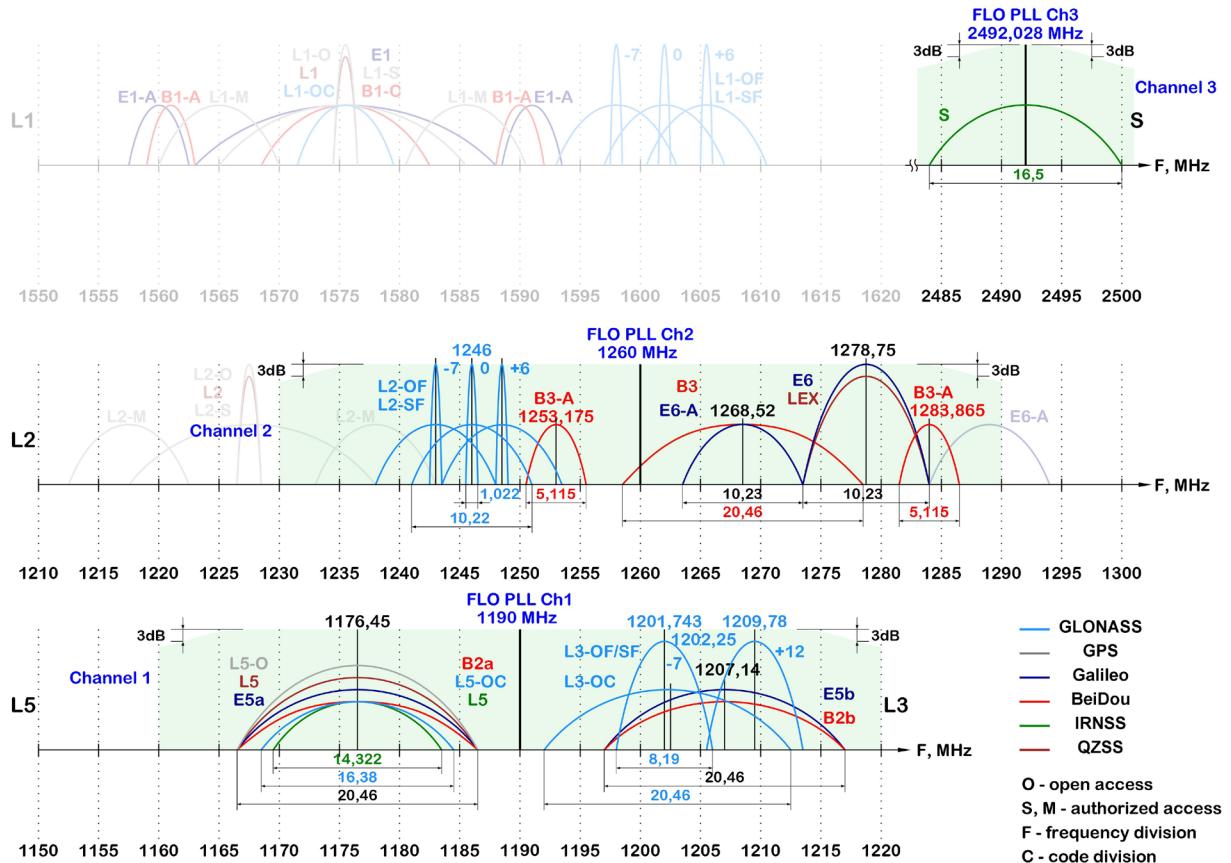
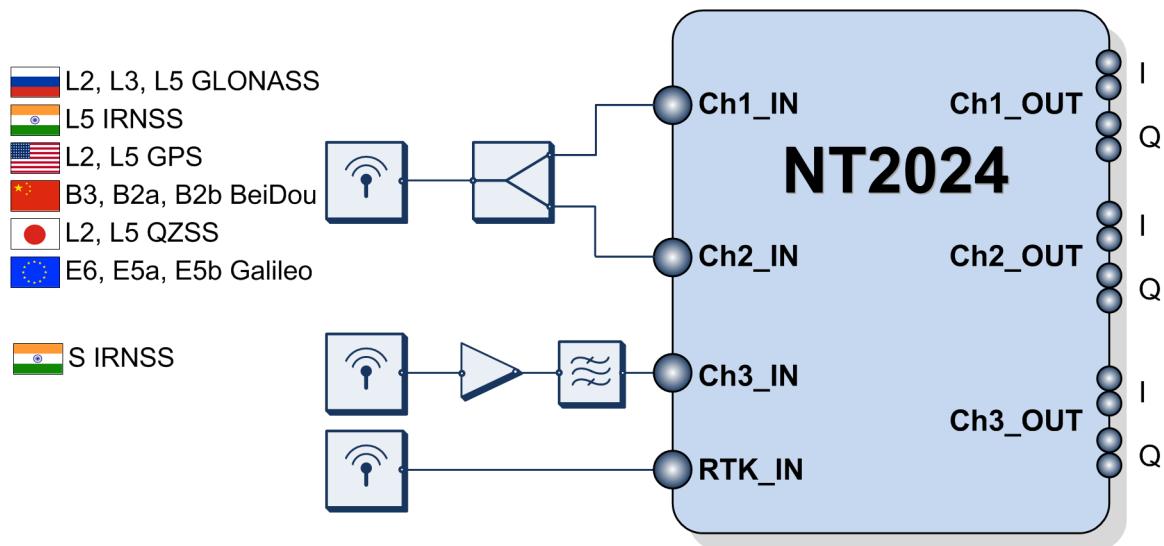
NT2024 does also integrate 3 fractional-N synthesizers that have the common reference (TCXO) input making LO signals coherent in terms of frequency. Wide list of attractive features and high level of customization make NT2024 capable to meet a demand of researchers and OEM developers in special applications: high precision positioning, goniometric, driverless car systems, professional drones and related areas.

4 TYPICAL APPLICATION

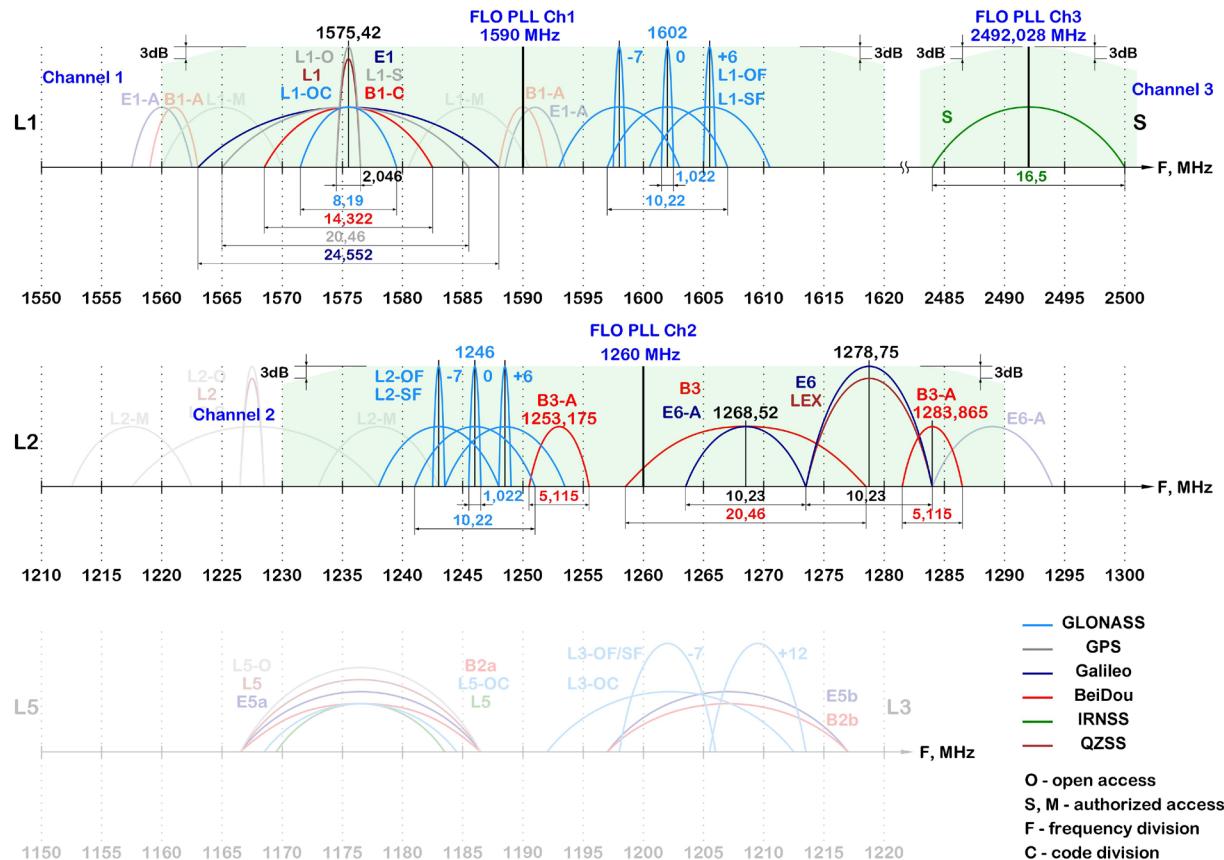
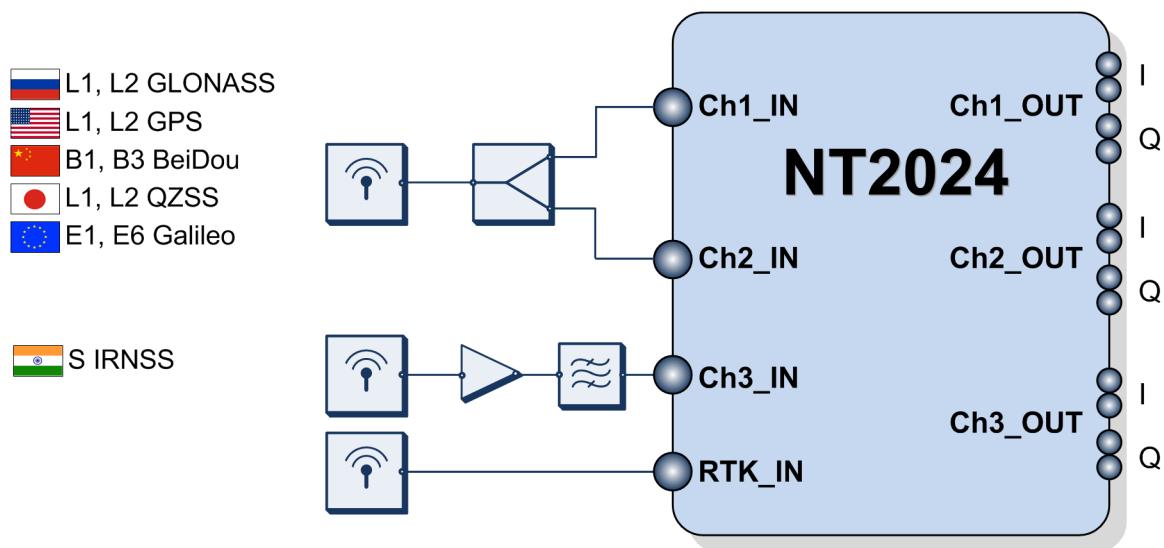
4.1 APPLICATION EXAMPLE 1



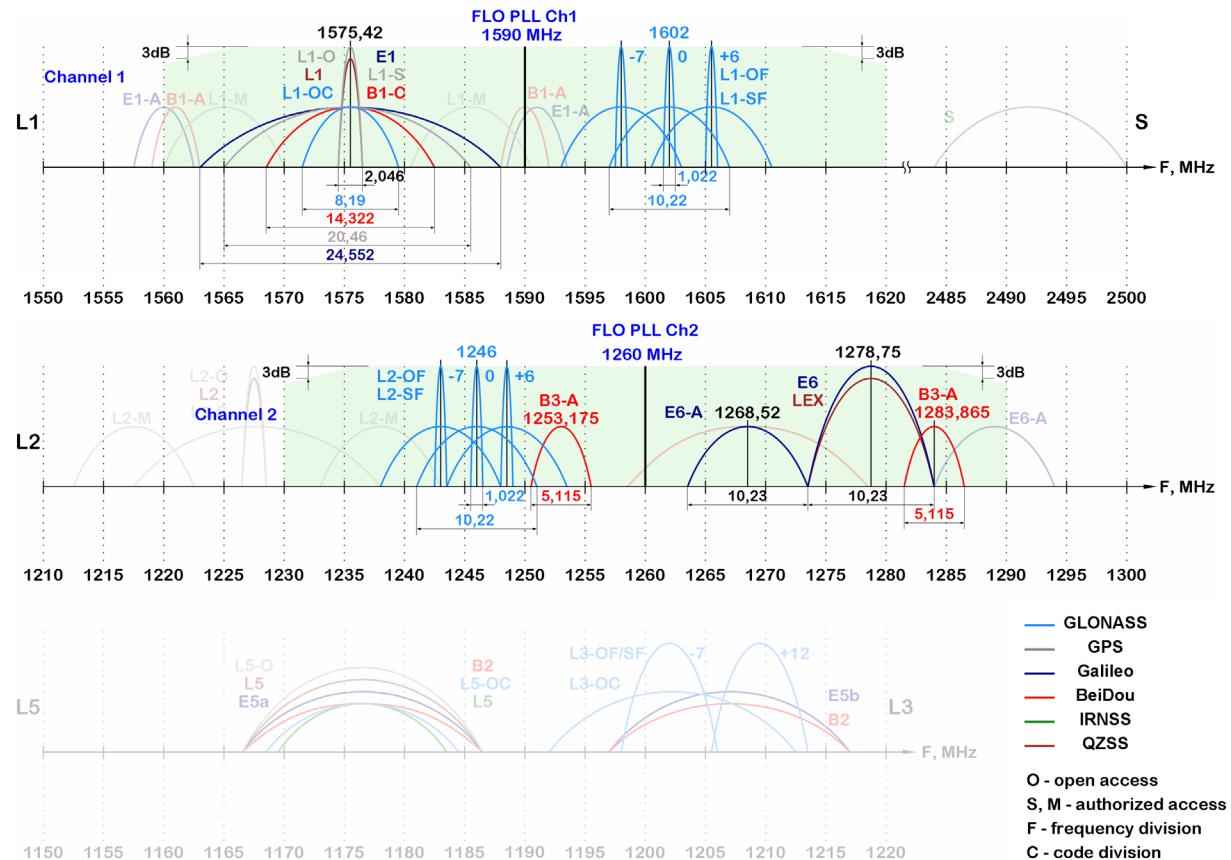
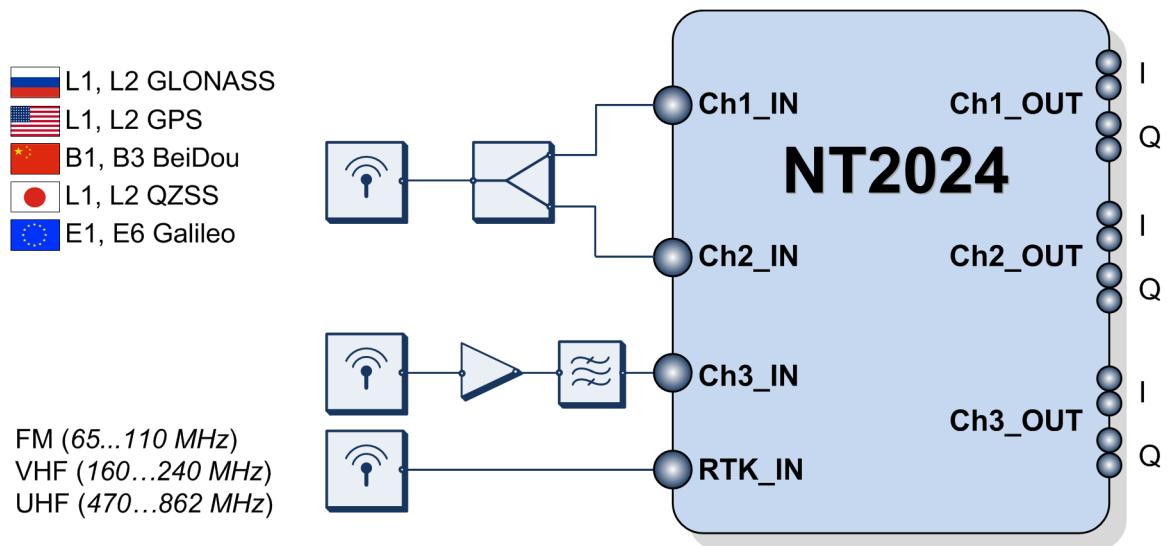
4.2 APPLICATION EXAMPLE 2



4.3 APPLICATION EXAMPLE 3



4.4 APPLICATION EXAMPLE 4



5 LAYOUT DESCRIPTION

IC dimensions are given in the table 2

Table 1: Block dimensions

Dimension	Value	Unit
Height	6 735	um
Width	6 445	um

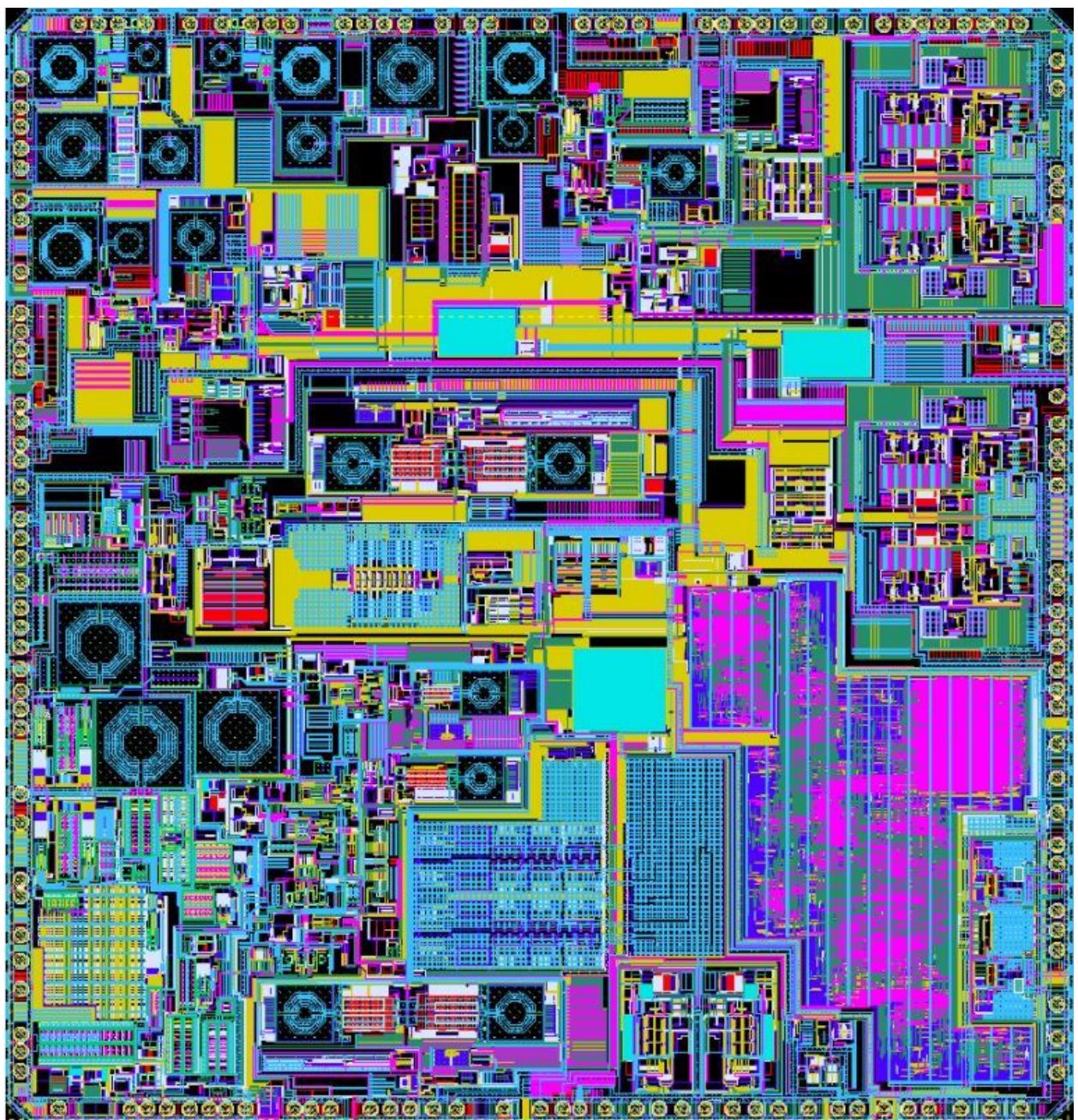


Figure 1: Block layout

6 OPERATING CHARACTERISTICS

6.1 TECHNICAL CHARACTERISTICS

Technology _____ TSMC BiCMOS 0.18 um
 Status _____ silicon proven
 Area _____ 43.5 mm²

6.2 DC ELECTRICAL CHARACTERISTICS

The values of electrical characteristics are specified for $V_{cc} = 2.8$ V to 3.6V, $T_a = -40\dots+85^\circ\text{C}$. Typical values are at $V_{cc} = 3.0$ V, $T_a = +27^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Condition	Value			Unit
			min	typ.	max	
Overall						
Supply voltage	V_{cc}	-	2.8	3.0	3.6	V
Current consumption	I_{cc}	Mode 1	-	62	-	mA
		Mode 2	-	144	-	
		Mode 3	-	137	-	
		Mode 4	-	31	-	
		Mode 5	-	33	-	
		Mode 6	-	82	-	
	I_{stb}	Stand-by mode	-	-	2.0	uA
Die temperature measurement range	T_j	-	-40	27	+100	°C
Die temperature measurement accuracy	ΔT_j	-	-	-	±5	°C
Temperature sensor DAC resolution	K	-	-	10	-	bit
Input logic-level high	V_{IL}	-	-0.25	-	0.3	V
Input logic-level low	V_{IH}	-	$0.7V_{cc}$	-	$V_{cc} + 0.25$	V
Channels #1 and #2						
AA output voltage drop	ΔV_{AA}	From supply voltage V_{cc} . Nominal value. Note 1	-	0.16	-	V
Short-circuit protection current	I_{AS}	Nominal value. Note 2	-	16.0	-	mA
AA detection current	I_{AW}	Nominal value. Note 3	-	1.8	-	mA
IFA output DC level	$V_{IFA_dif_ch1\&2}$	-	-	$V_{cc} - 1.17$	-	V
		-	-	$V_{cc} - 1.36$	-	
Output logic-level high (digital output)	V_{OH_dig}	For outputs ch1_Ip (Sign), ch1_In (Magn), ch2_Ip (Sign), ch2_In (Magn).	$V_{cc} - 0.5$	$V_{cc} - 0.2$	V_{cc}	V
Output logic-level low (digital output)	V_{OL_dig}	Load current 2 mA	0	0.04	0.2	V
Clock output DC level	$V_{DC_CLK_ch1\&2}$	Preset1	-	$1.16 - V_{clk_ch1\&2}/4^*$	-	V
		Preset2	-	$1.74 - V_{clk_ch1\&2}/4^*$	-	
		Preset3	-	$2.32 - V_{clk_ch1\&2}/4^*$	-	
		Preset4	-	$V_{cc} - V_{clk_ch1\&2}/4^*$	-	
Channel #3						
IFA output DC level	$V_{IFA_dif_ch3}$	Preset1	-	$V_{cc} - 1.25$	-	V
		Preset2	-	$V_{cc} - 1.35$	-	
		Preset3	-	$V_{cc} - 1.50$	-	
		Preset4	-	$V_{cc} - 1.65$	-	
LNA AGC control voltage	V_{AGCLNA}	Maximum gain	-	V_{cc}	-	V
		Minimum gain	-	0	-	

Table “DC electrical characteristics” (continue)

Parameter	Symbol	Condition	Value			Unit
			min	typ.	max	
MIX AGC control voltage	V_{AGCMix}	Maximum gain	-	V_{cc}	-	V
		Minimum gain	-	0	-	
IF AGC control voltage	V_{AGCIF}	Maximum gain	-	$V_{cc} - 0.1$	-	V
		Minimum gain	-	0.1	-	
Clock output DC level	$V_{DC_CLK_ch3}$	Preset1	-	$1.10 - V_{clk_ch3}/2^{**}$	-	V
		Preset2	-	$1.65 - V_{clk_ch3}/2^{**}$	-	
		Preset3	-	$2.25 - V_{clk_ch3}/2^{**}$	-	
		Preset4	-	$V_{cc} - V_{clk_ch3}/2^{**}$	-	

Notes:

* - $V_{clk_ch1\&2}$ refer to table «AC electrical characteristics» on page 16

** - V_{clk_ch3} refer to table «AC electrical characteristics» on page 18

Notes:

1. Voltage drop value is evaluated from the equation $\Delta V = 0.1V + (2\Omega \times IAA)$, where IAA is active antenna current.
2. Current IAS = Imax, where Imax is active antenna maximal current
3. Current IAW = Imin, where Imin is active antenna minimal current

Modes:

1. **Channel 1:** L1 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 2: L2 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 3: disable.
2. **Channel 1:** L1 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 2: L2 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 3: S band, IQ IRNSS, analog differential output, $V_{out_p-p} = 430$ mV
3. **Channel 1:** L1 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 2: L2 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 3: RTK.
4. **Channel 1:** L1 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 2: disabled;
Channel 3: disabled.
5. **Channel 1:** disable;
Channel 2: L2 band, IQ GNSS, analog differential output, $V_{out_p-p} = 230$ mV
Channel 3: disable.
6. **Channel 1:** disabled;
Channel 2: disabled;
Channel 3: S band, IQ IRNSS, analog differential output, $V_{out_p-p} = 430$ mV

6.3 AC ELECTRICAL CHARACTERISTICS

The values of electrical characteristics are specified for $V_{cc} = 2.8 \text{ V}$ to 3.6 V , $T_a = -40 \dots +85^\circ\text{C}$. Typical values are at $V_{cc} = 3.0 \text{ V}$, $T_a = +27^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Condition	Value			Unit	
			min	typ.	max		
Overall							
Reference frequency range	F_{REF}	-	1	24.84	30	MHz	
Reference input level	REF_{IN}	-	0.8	1	2	V	
Channels #1 and #2							
Overall							
Input frequency range	F_{IN}	L1 band	1530	-	1610	MHz	
		L2, L3 or L5 band	1164	-	1300		
Noise figure referred to LNA1 input	NF_{IN_LNA1}	$G_{IF} > 45 \text{ dB}$	-	2.3	-	dB	
1dB compression point referred to LNA1 input	P_{1dB_LNA1}	$G_{IFA} = \text{min.}$	-	-51	-	dBm	
Intercept point 3 rd order referred to LNA1 input	$IIP3_{LNA1}$	$G_{IFA} = \text{min.}$	-	-40	-	dBm	
Noise figure referred to LNA2 input	NF_{IN_LNA2}	$G_{IF} = \text{min.}$	-	6.8	-	dB	
1dB compression point referred to LNA2 input	P_{1dB_LNA2}	$G_{IFA} = \text{min.}$	-	-34	-	dBm	
Intercept point 3 rd order referred to LNA2 input	$IIP3_{LNA2}$	$G_{IFA} = \text{min.}$	-	-23	-	dBm	
Noise figure referred to mixer input	NF_{IN_MIX}	$G_{IF} > 45 \text{ dB}$	-	8	-	dB	
1dB compression point referred to mixer input	P_{1dB_MIX}	$G_{IFA} = \text{min.}$	-	-37	-	dBm	
Intercept point 3 rd order referred to mixer input	$IIP3_{MIX}$	$G_{IFA} = \text{min.}$	-	-28	-	dBm	
LNA1							
LNA1 noise figure	NF_{LNA1}	L1 band	-	2.0	-	dB	
		L2, L3 or L5 band	-	1.8	-		
LNA1 gain	G_{LNA1}	L1 band	-	14.3	-	dB	
		L2, L3 or L5 band	-	14	-		
LNA1 input VSWR	$VSWR_{LNA1_in}$	50 Ω	L1 band	-	1.5	-	
			L2, L3 or L5 band	-	1.4		
LNA1 output VSWR	$VSWR_{LNA1_out}$	50 Ω	L1 band	-	1.8	-	
			L2, L3 or L5 band	-	2		
LNA1 input 1dB compression point	P_{1dB_LNA1}		L1 band	-	-21	dBm	
			L2, L3 or L5 band	-	-25		
LNA1 intercept point 3 rd order	$IIP3_{LNA1}$		L1 band	-	-10	dBm	
			L2, L3 or L5 band	-	-9		
Input impedance	R_{in_LNA1}		-	-	50	-	Ω
Output impedance	R_{out_LNA1}		-	-	50	-	Ω
LNA2							
LNA2 noise figure	NF_{LNA2}	L1 band	-	5.8	-	dB	
		L2, L3 or L5 band	-	5.3	-		
LNA2 gain	G_{LNA2}	L1 band	-	1.29	-	dB	
		L2, L3 or L5 band	-	2.1	-		
LNA2 input VSWR	$VSWR_{LNA2_in}$	50 Ω	L1 band	-	1.6	-	
			L2, L3 or L5 band	-	1.22		
LNA2 output VSWR	$VSWR_{LNA2_out}$	50 Ω	L1 band	-	1.8	-	
			L2, L3 or L5 band	-	1.65		
LNA2 input 1dB compression point	P_{1dB_LNA2}		L1 band	-	-4	dBm	
			L2, L3 or L5 band	-	-3.7		

Table “AC electrical characteristics” (continue)

Parameter	Symbol	Condition	Value			Unit	
			min	typ.	max		
LNA2 intercept point 3 rd order	IIP3 _{LNA2}	L1 band	-	3.6	-		
		L2, L3 or L5 band	-	3.6	-		
Input impedance	R _{in LNA2}	-	-	50	-	Ω	
Output impedance	R _{out LNA2}	-	-	50	-	Ω	
Mixer							
Mixer input VSWR	VSWR _{IN_MIX}	L1 band, 50 Ω, F = 1589.76 MHz	-	2	-	-	
		L2, L3 or L5 band, 50 Ω, F = 1217.16 MHz	-	2	-		
PPF							
Image rejection	IR	L1 band	-	28	-	dB	
		L2, L3 or L5 band	-	30	-		
LPF&IFA							
Sinusoidal/noise signal peak-to-peak voltage at the differential linear outputs	V _{p-p}	510 Ohm load resistance	-	200/480	-	mV	
Gain	G	Minimal	-	10	-	dB	
		Maximal	-	58	-		
AGC range	ΔG	-	48	-	-	dB	
Synthesizer							
LO frequency	F _{LO}	Adjustable	1165	-	1606	MHz	
LO phase noise	PN _{LO}	At 10 kHz frequency offset, F _{REF} = 24.84 MHz	L1 band	-	-89	-	
			L2, L3 or L5 band	-	-89	-	
		At 100 kHz frequency offset, F _{REF} = 24.84 MHz	L1 band	-	-91.5	-	
			L2, L3 or L5 band	-	-89	-	
		At 1 MHz frequency offset, F _{REF} = 24.84 MHz	L1 band	-	-111	-	
			L2, L3 or L5 band	-	-116	-	
Clock frequency	F _{CLK}	F _{LO} /R, where R = CDIV<9:0>	1.55	-	198.72	MHz	
Peak-to-peak voltage at the clock output at typical frequency	V _{clk_ch1&2}	Preset1, ECL	-	0.50	-	V	
		Preset2, ECL		0.72			
		Preset3, ECL		0.91			
		Preset4, ECL		1.07			
		Preset5, CMOS	-	0.91	-		
		Preset6, CMOS		1.60			
		Preset7, CMOS		2.28			
		Preset8, CMOS		2.95			
Channel #3							
Overall							
Input frequency range	F _{IN_ch3}	IRNSS S-band	2170	-	2500	MHz	
		FM	65	-	110		
		VHF	160	-	240		
		UHF	470	-	862		
Noise figure	NF _{ch3}	IRNSS S-band	-	7.1	-	dB	
		FM	-	4.5	-		
		VHF	-	4.5	-		
		UHF	-	4.0	-		
Input VSWR	VSWR _{IN_ch3}	50 Ω	IRNSS S-band	-	4.0	-	
			FM	-	1.8		
			VHF	-	2.0		
			UHF	-	2.0		

Table “AC electrical characteristics” (continue)

Parameter	Symbol	Condition	Value			Unit
			min	typ.	max	
Input 1dB compression point	P _{1dB RF_ch3}	IRNSS S-band	G _{RF} = max, G _{IF} = min	-	-17	dBm
			G _{RF} = min, G _{IF} = min	-	13	
		FM, VHF, UHF	G _{RF} = max, G _{IF} = min	-	-28	
			G _{RF} = min, G _{IF} = min	-	10	
Intercept point 3rd order	IIP3 _{RF_ch3}	IRNSS S-band	G _{RF} = max, G _{IF} = min	-	-9	dBm
			G _{RF} = min, G _{IF} = min	-	22	
		FM, VHF, UHF	G _{RF} = max, G _{IF} = min	-	-20	
			G _{RF} = min, G _{IF} = min	-	20	
Overall voltage gain	G _{ch3}	-	-	90	-	dB
IQ phase accuracy	Δφ _{ch3}	I/Q phase error at 1 MHz	-3	-	+3	degrees
LNA AGC range	ΔG _{LNA_ch3}	IRNSS S-band	G = max	-	16.4	dB
			G = min	-	-11.7	
		FM, VHF, UHF	G = max	-	18.1	
			G = min	-	-17	
MIX AGC range	ΔG _{Mix_ch3}	IRNSS S-band	G = max	-	7.0	dB
			G = min	-	3.0	
		FM, VHF, UHF	G = max	-	11.6	
			G = min	-	3.0	
IFA AGC range	ΔG _{IFA}	G = max	-	-7	-	dB
		G = min	-	73	-	
IFA&LPF						
Nominal output voltage	V _{out_ch3}	Minimal	-	150	-	mV
		Default	-	430	-	
		Maximal	-	1500	-	
IQ amplitude output voltage accuracy	ΔA _{ch3}	-	-	28.5	-	mV
Stopband attenuation	S _A	F _{cut_LPF} = 3.80 MHz	F = 6 MHz	-	20	dB
			F = 8 MHz	-	39	
Output impedance	R _{out}	Differential	-	1.5	-	kΩ
LPF bandwidth	BW _{LPF}	F _{cut_LPF} = 1.60 MHz	-	1.6	-	MHz
			-	3.8	-	
			-	4.9	-	
Synthesizer						
LO phase noise	PN _{LO_ch3}	At 10 kHz frequency offset, F _{REF} = 24.84 MHz	IRNSS S-band	-	-85	dBc/Hz
			FM	-	-108	
			VHF	-	-103	
			UHF	-	-95	
		At 100 kHz frequency offset, F _{REF} = 24.84 MHz	IRNSS S-band	-	-87	
			FM	-	-110	
			VHF	-	-105	
			UHF	-	-98	
		At 1 MHz frequency offset, F _{REF} = 24.84 MHz	IRNSS S-band	-	-115	
			FM	-	-130	
			VHF	-	-128	
			UHF	-	-117	
N divider ratio	N	IRNSS S-band	56	-	2047	-
		FM	16	-	1023	
Fractional-N resolution	Res	-	-	24	-	bit
R divider ratio	R	-	1	-	31	-

Table “AC electrical characteristics” (continue)

Parameter	Symbol	Condition	Value			Unit
			min	typ.	max	
VCO frequency range	F _{VCO}	VCO 1	900	-	1300	MHz
		VCO 2	1250	-	1820	
		VCO 3	4340	-	5000	
Comparison frequency	F _{CPC}	-	1	24.84	30	MHz
Peak-to-peak voltage at the clock output at typical frequency	V _{clk_ch3}	Preset1, ECL	-	0.57	-	V
		Preset2, ECL	-	0.85	-	
		Preset3, ECL	-	1.14	-	
		Preset4, ECL	-	1.38	-	
		Preset5, CMOS	-	1.12	-	
		Preset6, CMOS	-	1.70	-	
		Preset7, CMOS	-	2.25	-	
		Preset8, CMOS	-	Vcc	-	

7 DELIVERABLES

IP contents:

- Datasheet
- Layout View (GDSII)
- Evaluation kit based on packaged IC
- Characterization Report
- Behavioral Model
- SPICE netlist (.cdl)
- Integration Support